

*Citations for :* **Dielectric Targets** *Ion = Xe*

<b>Pub. Year</b>	<b>Authors, Title, Journal Citation and Comments</b>	<b>Citation Numb</b>
<b>1963</b>	McCargo, M. Davies, J. A. Brown, F. <b>'Range of Xe133 and Ar41 Ions of keV Energies in Tungsten'</b> <i>Can. J. Phys., 41, 1231-44 (1963)</i> <i>Comment : R, dR. 2-200 keV 133Xe, 41Ar -&gt; W, 40 keV 85Kr -&gt; WO3</i>	<b>1963-McCa2</b>
<b>1964</b>	Domeij, B. McCargo, M. Davies, J. A. Brown, F. <b>'Ranges of Heavy Ions in Amorphous Oxides'</b> <i>Bull. Am. Phys. Soc., 9, 109a (1964)</i> <i>Comment : R, dR. 5-160 keV Na, Kr, Xe -&gt; Al2O3</i>	<b>1964-Dome3</b>
<b>1966</b>	Whitton, J. L. Matzke, Hj. <b>'The Effect of Crystallinity and Bombardment Dose on the Penetration of 40 keV Xenon Ions in Ionic Crystals and Ceramics'</b> <i>Can. J. Phys., 44, 2905-14 (1966)</i> <i>Comment : R, dR. 40 keV Xe -&gt; NaCl, KBr, MgO, SiO2, UO2</i>	<b>1966-Whit</b>
<b>1967</b>	Jespersgaard, P. Davies, J. A. <b>'Ranges of Na, K, W, and Xe Ions in Amorphous Al2O3 in the Energy Region 40-1000 keV'</b> <i>Can. J. Phys., 45, 2983-94 (1967)</i> <i>Comment : R, dR. 40-1000 keV Na, K, Kr, Xe -&gt; Al2O3</i>	<b>1967-Jesp</b>
<b>1970</b>	Dearnaley, G. <b>'Ion Penetration'</b> <i>European Conference on Ion Implantation, Reading, 162-171 (1970)</i> <i>Comment : R. 10 keV-2 MeV Na, K, Kr, Xe, Ne -&gt; Al2O3</i>	<b>1970-Dear</b>
<b>1970</b>	Santry, D. C. Sitter, C. W. <b>'Range and Retention Studies of 40-keV Ions in Solids, in H'</b> <i>Wagner, W. Walcher (Ed.) Proc. Int. Conf. Elmagn. Isotope Separators and Their Techniques. Marburg, P. 505-24 (1970)</i> <i>Comment : R, dR. 40 keV C, O, P, Co, Tl, Na, P, Co, Zn, Se, Kr, Hf, Cs, Ag, I, Xe -&gt; Au, W, WO3</i>	<b>1970-Sant</b>
<b>1970</b>	Schalch, D. Scharmann, A. <b>'Eindringtiefen von Ionen in CaF2-Und Rb-Aufdampfschichten'</b> <i>Z. Angew. Phys., 29, 111-13 (1970)</i> <i>Comment : R. 10-80 keV H, He, Ne, Ar, Kr, Xe -&gt; CaF2, Rb</i>	<b>1970-Scha</b>
<b>1975</b>	Andersen, H. H. Bottiger, J. WolderJorgensen, H. <b>'Ranges of Ions with Z1 &gt; 54 in Al and Al2O3'</b> <i>Appl. Phys. Letters, 26, 678-79 (1975)</i> <i>Comment : R, dR. (75-100 keV) Cs, Xe, Eu, Au, Tl -&gt; Al, Al2O3</i>	<b>1975-Ande</b>
<b>1976</b>	Pringle, J. P. S. <b>'A Comparison of Sectioning Methods used to Measure Concentration Profiles in Anodic Oxides'</b> <i>Can. J. Phys., 54, 56-65 (1976)</i> <i>Comment : R. dR. (10-160 keV) Na, Ar, K, Kr, Xe -&gt; Al2O3, Ta2O5, WO3, Ta2O5</i>	<b>1976-Prin</b>

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<b>1980</b>	Bimbot, R. Gardes, D. Geissel, H. Kitahara, T. Armbuster, P. <b>'Stopping Power Measurements for 3-5 MeV/amu Kr, Xe, Pb and U in Solids'</b> <i>Nucl. Inst. Methods, 174, 231-236 (1980)</i> <i>Comment : S. Kr, Xe, Pb, U (3-5 MeV/amu) -&gt; C, Al, Ti, Ni, Zr, Ag, Ta, Ir, Au, Mylar, Hostaphan</i>	<b>1980-Bimb</b>
<b>1988</b>	Balanzat, E. Jousset, J. C. Toulemonde, M. <b>'Latent Tracks Induced by Heavy Ions in the GeV Energy Range: Results at GANIL'</b> <i>Nucl. Inst. Methods, B32, 368-376 (1988)</i> <i>Comment : R. O, Ar, Kr, Mo, Xe, U (4-85 MeV/amu) -&gt; Polymers, Insulators, Superconductors: Track Analysis</i>	<b>1988-Bala</b>
<b>1988</b>	Grande, P. L. Fichtner, P. F. P. Behar, M. Zawislak, F. C. <b>'Range Profiles of Medium and Heavy Ions Implanted into SiO2'</b> <i>Nucl. Inst. Methods, B35, 17-20 (1988)</i> <i>Comment : R. As, Cs, Xe, Eu, Yb (10-200 keV) -&gt; SiO2</i>	<b>1988-Gran</b>
<b>1995</b>	Peterson, F. Enge, W. <b>'Energy Loss Dependent Transversal Etching Rates of Heavy Ion Tracks in Plastic'</b> <i>Rad. Meas., 25, 43-46 (1995)</i> <i>Comment : S. Au, Xe (10-480 MeV/amu) -&gt; Makrofol</i>	<b>1995-Pete</b>
<b>1996</b>	Srivastava, A. Laldawngliana, C. Sinha, D. Ghosh, S. Dwivedi, K.K. <b>'Range and Energy Loss of Ni and Xe Ions in Hostaphan'</b> <i>Indian J. Pure Appl. Phys., 34, 371-375 (1996)</i> <i>Comment : S.R. Ni, Xe -&gt; hostaphan</i>	<b>1996-Sriv</b>